

DEC 21 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/075,193
Filing Date February 13, 2002
Inventor Shenlin Chen et al.
Assignee Micron Technology, Inc.
Group Art Unit 2813
Examiner Huynh, Y.
Attorney's Docket No. MI22-1927
Title: Methods of Forming a Capacitor Structure

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

References -See Attached Form PTO-1449

The Examiner's attention is directed to the references which are listed on the attached Form PTO-1449, copies of which are attached. No admission is made regarding whether all the submitted references are prior art.

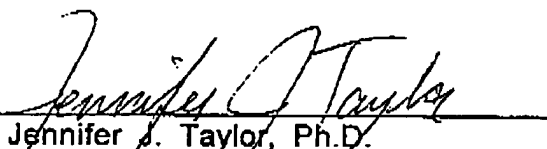
Citation of the referenced art is respectfully requested.

Respectfully submitted,

Dated:

October 21, 2003

By:


Jennifer J. Taylor, Ph.D.
Reg. No. 48,711

Form PTO-1449

ATTY. DOCKET NO.
M123-1927SERIAL NO.
10/075,193LIST OF ART CITED BY APPLICANT
(Use several sheets if necessary)APPLICANT
Shenlin Chen et al.FILING DATE
February 13, 2002GROUP
2813

U.S. PATENT DOCUMENTS

*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	AA	2001/0003053 A1	05-2001	Kwok et al.			
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						

FOREIGN PATENT DOCUMENTS

		Document Number	Date	Country	Class	Subclass	Translation	
							Yes	No
	AM							
	AN							
	AO							
	AP							
	AQ							

OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.)

	AR		
	AS		
	AT		

EXAMINER

DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.